

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- $BV_{CE0} > -60V$
- $I_C = -3A$ High Continuous Collector Current
- I_{CM} up to $-6A$ Peak Pulse Current
- 2W Power Dissipation
- Complementary PNP Type: DXT651Q
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

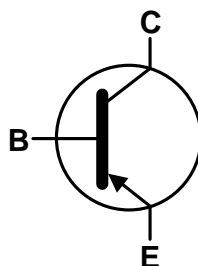
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.052 grams (Approximate)

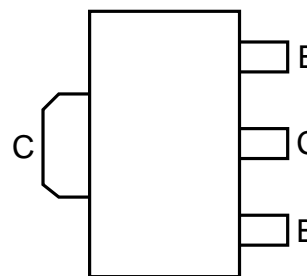
SOT89



Top View



Device Symbol



Top View
Pinout

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT751Q-13	Automotive	KP2	13	12	2,500

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT89



KP2 = Product Type Marking Code
 DII = Manufacturer's Marking Code
 YWW = Date Code Marking
 Y = Last digit of year (ex: 6 = 2016)
 WW = Week code (01 – 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

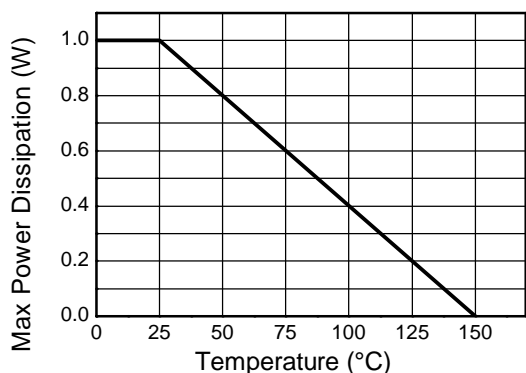
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	I _C	-3	A
Peak Pulse Collector Current	I _{CM}	-6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

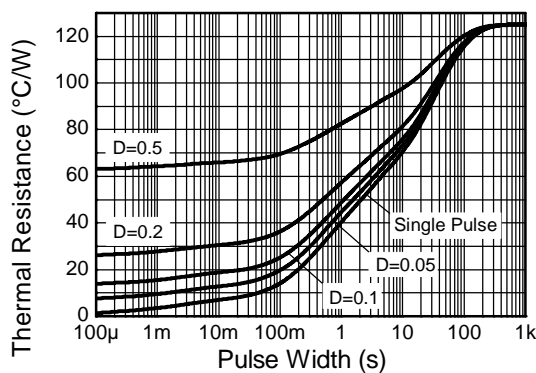
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	1	W
		2	
Thermal Resistance, Junction to Ambient Air	R _{θJA}	125	°C/W
		62.5	
Thermal Resistance, Junction to Leads	R _{θJL}	6.0	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
- 6. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
 - 7. Same as note (5), except the device is mounted on 40mm x 40mm x 1.6mm FR4 PCB.
 - 8. Thermal resistance from junction to solder-point (on the exposed collector pad).

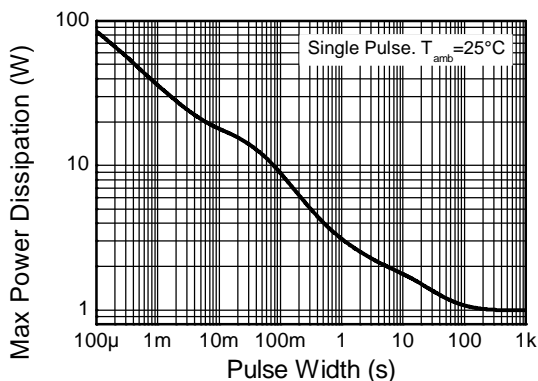
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CB0}	-80	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	—	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CB0}	—	—	-0.1 -10	μA	V _{CB} = -60V V _{CB} = -60V, T _A = +100°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	-0.1	μA	V _{EB} = -4V
ON CHARACTERISTICS (Note 9)						
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	-0.08 -0.2	-0.3 -0.6	V	I _C = -1A, I _B = 100mA I _C = -3A, I _B = 300mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	-0.90	-1.25	V	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	—	-0.8	-1	V	V _{CE} = -2V, I _C = -1A
DC Current Gain	h _{FE}	70 100 80 40	200 180 160 140	— 300 — —	—	V _{CE} = -2V, I _C = -50mA V _{CE} = -2V, I _C = -500mA V _{CE} = -2V, I _C = -1A V _{CE} = -2V, I _C = -2A
SMALL-SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	100	145	—	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance	C _{obo}	—	—	30	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on} t _{off}	— —	45 200	— —	ns ns	V _{CC} = -10V, I _C = -500mA, I _{B1} = -I _{B2} = -50mA

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

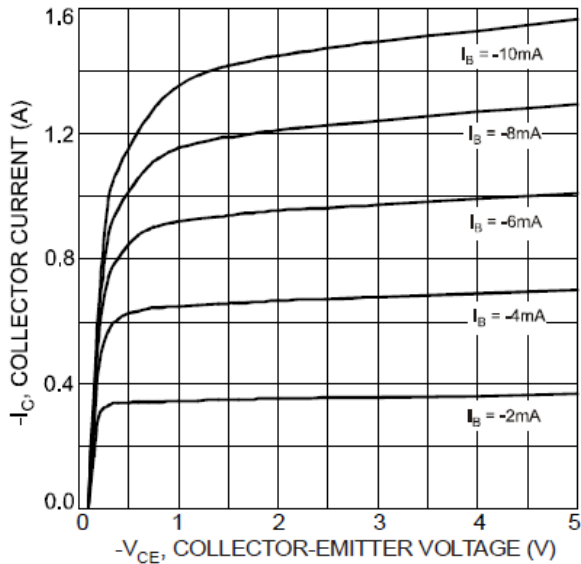


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage

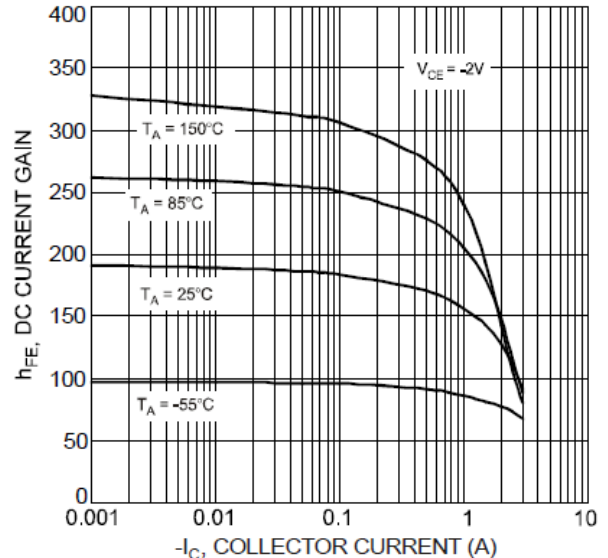


Fig. 3 Typical DC Current Gain vs. Collector Current

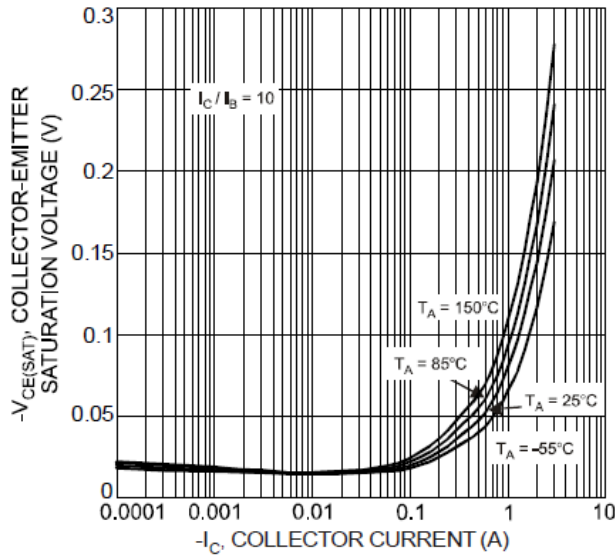


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

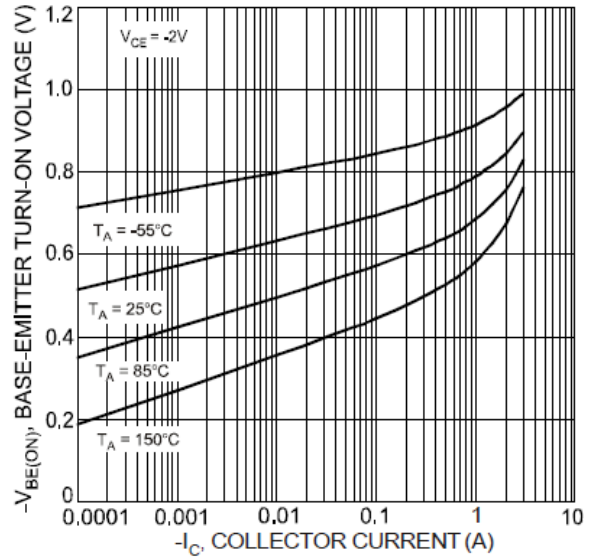


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

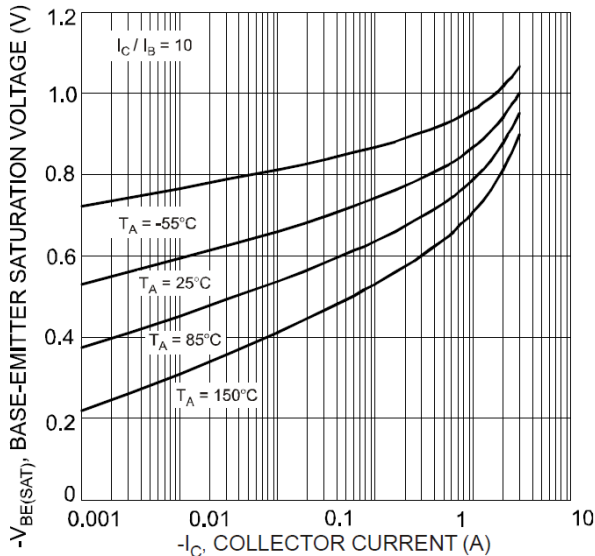


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

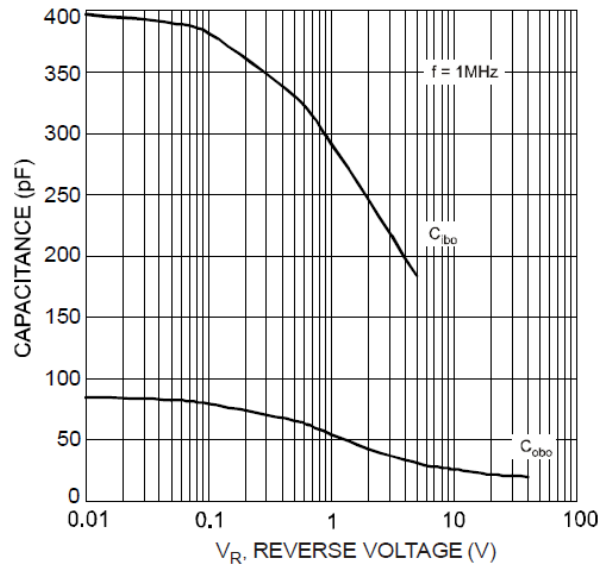


Fig. 7 Typical Capacitance Characteristics

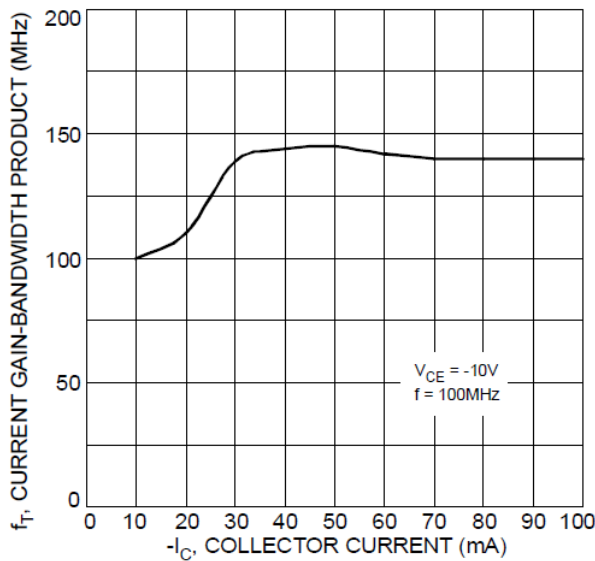
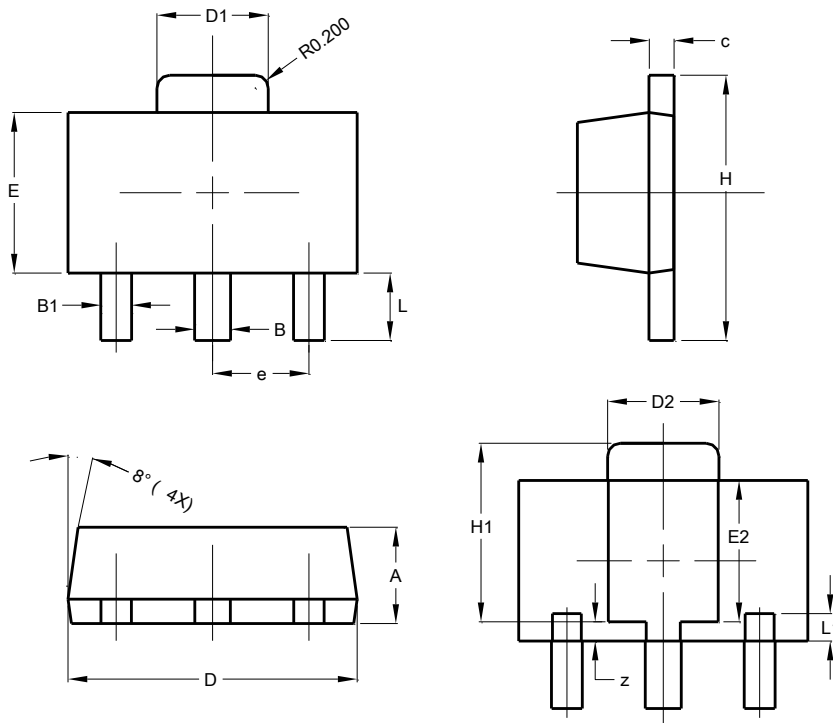


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

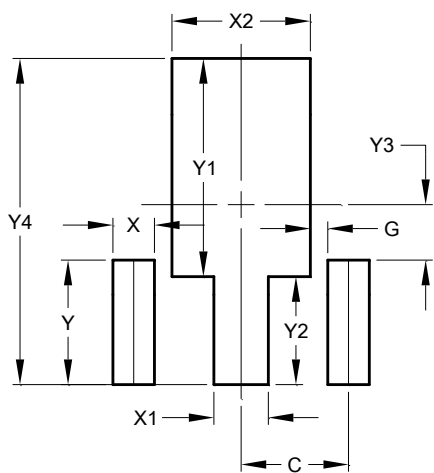
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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